## NSN 5962-00-301-3457

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View Online at https://aerobasegroup.com/nsn/5962-00-301-3457

Body Length:
Between 0.630 inches and 0.775 inches
Body Width:
Between 0.275 inches and 0.310 inches
Body Height:
Between 0.150 inches and 0.160 inches
Operating Tempurature Range:
55.0/+125.0 degrees celsius
Storage Tempurature Range:
65.0/+150.0 degrees celsius
Features Provided:
Hermetically sealed and programmable and programmed and w/open collector
nclosure Material:
Ceramic and glass
nclosure Configuration:
Dual-in-line
Output Logic Form:
Transistor-transistor logic
nput Circuit Pattern:
10 input
Terminal Surface Treatment:
Gold
Voltage Rating And Type Per Characteristic:
5.5 volts power source
Time Rating Per Chacteristic:
90.00 nanoseconds propagation delay time, low to high level output and 90.00 nanoseconds propagation delay time, high to low level
putput
Memory Device Type:
Rom
Precious Material And Location:
Terminal surface gold
Precious Material:
Gold
Test Data Document:
92755-20a3535 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.
excludes any specification, standard or other document that may be referenced in a basic governing drawing)
Terminal Type And Quantity:
16 printed circuit
Shelf Life:
N/a

**Demilitarization:** Yes - demil/mli

**Unit Of Measure:** 

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